

## Carbon-based optoelectronics on silicon using semiconducting single wall carbon nanotubes

Matteo Balestrieri, A. Keita, Elena Duran-Valdeiglesias, Francesco Sarti, Niccolò Caselli, W. Zhang, C Alonso-Ramos, Xavier Le Roux, H. Yang, Eric Cassan, et al.

► **To cite this version:**

Matteo Balestrieri, A. Keita, Elena Duran-Valdeiglesias, Francesco Sarti, Niccolò Caselli, et al.. Carbon-based optoelectronics on silicon using semiconducting single wall carbon nanotubes. E-MRS 2016, May 2016, Lille, France. cea-02351595

**HAL Id: cea-02351595**

**<https://hal-cea.archives-ouvertes.fr/cea-02351595>**

Submitted on 6 Nov 2019

**HAL** is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers.

L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.

Balestrieri M.

11:45	<p data-bbox="411 320 893 376"><b>Carbon-based optoelectronics on silicon using semiconducting single wall carbon nanotubes</b></p> <p data-bbox="411 394 1082 506">Authors : M. Balestrieri<sup>1</sup>, A. Keita<sup>1</sup>, E. Durán-Valdeiglesias<sup>2</sup>, F. Sarti<sup>3</sup>, N. Caselli<sup>3</sup>, W. Zhang<sup>2</sup>, C. Alonso-Ramos<sup>2</sup>, X. Le Roux<sup>2</sup>, H. Yang<sup>4</sup>, E. Cassan<sup>2</sup>, V. Bezugly<sup>4</sup>, F. Biccari<sup>3</sup>, A. Vinattieri<sup>3</sup>, G. Cuniberti<sup>4</sup>, M. Gurioli<sup>3</sup>, V. Derycke<sup>1</sup>, L. Vivien<sup>2</sup>, A. Filoramo<sup>1</sup></p> <p data-bbox="411 510 1082 678">Affiliations : 1 LICSEN, NIMBE, CEA, CNRS, Université Paris-Saclay, CEA Saclay 91191 Gif-sur-Yvette Cedex, France; 2 Univ Paris 11, CNRS UMR 8622, Inst. Elect. Fondamentale (IEF), F-91405 Orsay, France; 3 Department of Physics and LENS, University of Florence, Via Sansone 1, 50019 Sesto Fiorentino, Italy; 4 Technische Universitaet Dresden, Institute for Materials Science, 01062 Dresden, Germany;</p> <p data-bbox="411 696 1090 1330">Resume : Single-wall carbon nanotubes (SWNTs) are known for their exceptional physical properties ranging from mechanics to electronics and optics. These properties are expected to give rise to innovative applications, especially when nanotubes are incorporated in new functional devices. However, the conception of an effective SWNT-based electronic or optoelectronic technology faces three main concerns: the extraction of semiconducting SWNTs having the desired optoelectronic characteristics from the as-synthesized poly-disperse mixture; the deposition of high nanotube concentrations at desired areas to increase transport and optical performances and the alignment of nanotubes on the substrate. Using an effective polymer-assisted sorting approach, we obtain highly-selective separation of semiconducting SWNTs that can be coupled with optoelectronic silicon-based devices operating at the telecom wavelength of 1.5 <math>\mu\text{m}</math>. Our modified evaporative self-assembly approach can deposit concentrated SWNT networks with configurations varying from random to highly-oriented assembly. In the latter case, the obtained orientation is particularly favorable for device fabrication and operation. Several configurations enabling photo-detection and electroluminescence at the chip level are currently under investigation and the latest results will be presented. This work is funded by the European Union through the FP7 Project CARTOON (Contract FP7-618025).</p>	M.VIII.5	